

### FEATURES

#### Enhanced product features

- Supports defense and aerospace applications (AQEC)
- Military temperature range (–55°C to +125°C)
- Controlled manufacturing baseline
- One assembly/test site
- One fabrication site
- Enhanced product change notification
- Qualification data available on request

#### Low power, smallest pin-compatible octal DAC: 16 bits

#### 16-lead TSSOP

- On-chip 1.25 V, 5 ppm/°C reference
- Power down to 400 nA at 5 V, 200 nA at 3 V
- 2.7 V to 5.5 V power supply
- Guaranteed monotonic by design
- Power-on reset to zero scale or midscale
- 3 power-down functions
- Hardware LDAC and LDAC override function
- CLR function to programmable code
- Rail-to-rail operation

### APPLICATIONS

- Process control
- Data acquisition systems
- Portable battery-powered instruments

### GENERAL DESCRIPTION

The AD5668-EP is a low power, octal, 16-bit, buffered voltage-output digital-to-analog converter (DAC). It operates from a single 2.7 V to 5.5 V supply and is guaranteed monotonic by design.

The AD5668-EP has an on-chip reference with an internal gain of 2. The AD5668-EP has a 1.25 V, 5 ppm/°C reference, giving a full-scale output range of 2.5 V. The on-board reference is off at power-up, allowing the use of an external reference, and the internal reference is enabled via a software write.

The part incorporates a power-on-reset circuit that ensures that the DAC output powers up to 0 V and remains powered up at this level until a valid write takes place. The part contains a power-down feature that reduces the current consumption of the device to 400 nA at 5 V and provides software-selectable output loads while in power-down mode for any or all DAC channels. The outputs of all DACs can be updated simultaneously using the LDAC function, with the added functionality of user-selectable

### FUNCTIONAL BLOCK DIAGRAM

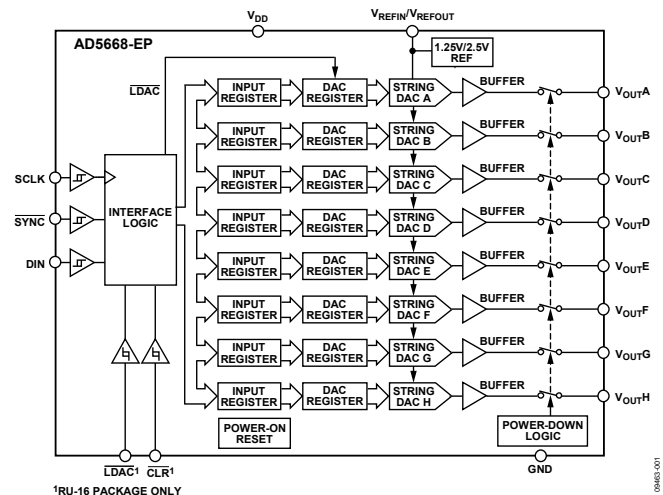


Figure 1.

DAC channels to simultaneously update. There is also an asynchronous CLR that updates all DACs to a user-programmable code—zero scale, midscale, or full scale.

The AD5668-EP uses a versatile 3-wire serial interface that operates at clock rates up to 50 MHz and is compatible with standard SPI, QSPI, MICROWIRE, and DSP interface standards.

Additional application and technical information can be found in the [AD5668](#) data sheet.

### PRODUCT HIGHLIGHTS

1. Octal, 16-bit DAC.
2. On-chip 1.25 V/2.5 V, 5 ppm/°C reference.
3. Available in 16-lead TSSOP.
4. Power-on reset to 0 V or midscale.
5. Power-down capability. When powered down, the DAC typically consumes 200 nA at 3 V and 400 nA at 5 V.

#### Rev. 0

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## REVISION HISTORY

10/10—Revision 0: Initial Version

## SPECIFICATIONS

$V_{DD} = 4.5\text{ V to }5.5\text{ V}$ ,  $R_L = 2\text{ k}\Omega$  to GND,  $C_L = 200\text{ pF}$  to GND,  $V_{REFIN} = V_{DD}$ . All specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Temperature range is  $-55^\circ\text{C}$  to  $+125^\circ\text{C}$ , typical at  $+25^\circ\text{C}$ .

**Table 1.**

Parameter	Min	Typ	Max	Unit	Conditions/Comments
<b>STATIC PERFORMANCE<sup>1</sup></b>					
Resolution	16			Bits	
Relative Accuracy		$\pm 8$	$\pm 21$	LSB	See Figure 4
Differential Nonlinearity			$\pm 1$	LSB	Guaranteed monotonic by design (see Figure 7)
Zero-Code Error		1	14	mV	All 0s loaded to DAC register (see Figure 9)
Zero-Code Error Drift		$\pm 2$		$\mu\text{V}/^\circ\text{C}$	
Full-Scale Error		$-0.2$	$-1$	% FSR	All 1s loaded to DAC register (see Figure 10)
Gain Error			$\pm 1$	% FSR	
Gain Temperature Coefficient		$\pm 2.5$		ppm	Of FSR/ $^\circ\text{C}$
Offset Error		$\pm 1$	$\pm 14$	mV	
DC Power Supply Rejection Ratio		$-80$		dB	$V_{DD} \pm 10\%$
DC Crosstalk (External Reference)		10		$\mu\text{V}$	Due to full-scale output change, $R_L = 2\text{ k}\Omega$ to GND or $V_{DD}$
		5		$\mu\text{V}/\text{mA}$	Due to load current change
		10		$\mu\text{V}$	Due to powering down (per channel)
DC Crosstalk (Internal Reference)		25		$\mu\text{V}$	Due to full-scale output change, $R_L = 2\text{ k}\Omega$ to GND or $V_{DD}$
		10		$\mu\text{V}/\text{mA}$	Due to load current change
<b>OUTPUT CHARACTERISTICS<sup>2</sup></b>					
Output Voltage Range	0		$V_{DD}$	V	
Capacitive Load Stability		2		nF	$R_L = \infty$
		10		nF	$R_L = 2\text{ k}\Omega$
DC Output Impedance		0.5		$\Omega$	
Short-Circuit Current		30		mA	$V_{DD} = 5\text{ V}$
Power-Up Time		4		$\mu\text{s}$	Coming out of power-down mode, $V_{DD} = 5\text{ V}$
<b>REFERENCE INPUTS</b>					
Reference Current		40	55	$\mu\text{A}$	$V_{REF} = V_{DD} = 5.5\text{ V}$ (per DAC channel)
Reference Input Range	0		$V_{DD}$	V	
Reference Input Impedance		14.6		k $\Omega$	
<b>REFERENCE OUTPUT</b>					
Output Voltage	1.247		1.253	V	At ambient
Reference Temperature Coefficient <sup>2</sup>		$\pm 5$		ppm/ $^\circ\text{C}$	
Reference Output Impedance		7.5		k $\Omega$	
<b>LOGIC INPUTS<sup>2</sup></b>					
Input Current			$\pm 3$	$\mu\text{A}$	All digital inputs
Input Low Voltage, $V_{INL}$			0.8	V	$V_{DD} = 5\text{ V}$
Input High Voltage, $V_{INH}$	2			V	$V_{DD} = 5\text{ V}$
Pin Capacitance		3		pF	
<b>POWER REQUIREMENTS</b>					
$V_{DD}$	4.5		5.5	V	All digital inputs at 0 or $V_{DD}$ , DAC active, excludes load current
$I_{DD}$ (Normal Mode) <sup>3</sup>					$V_{IH} = V_{DD}$ and $V_{IL} = \text{GND}$
$V_{DD} = 4.5\text{ V to }5.5\text{ V}$		1.3	1.8	mA	Internal reference off
$V_{DD} = 4.5\text{ V to }5.5\text{ V}$		2	2.6	mA	Internal reference on
$I_{DD}$ (All Power-Down Modes) <sup>4</sup>					
$V_{DD} = 4.5\text{ V to }5.5\text{ V}$		0.4	1	$\mu\text{A}$	$V_{IH} = V_{DD}$ and $V_{IL} = \text{GND}$

<sup>1</sup> Linearity calculated using a reduced code range of AD5668 (Code 512 to 65,024). Output unloaded.

<sup>2</sup> Guaranteed by design and characterization; not production tested.

<sup>3</sup> Interface inactive. All DACs active. DAC outputs unloaded.

<sup>4</sup> All eight DACs powered down.

# AD5668-EP

## AC CHARACTERISTICS

$V_{DD} = 2.7\text{ V to }5.5\text{ V}$ ,  $R_L = 2\text{ k}\Omega\text{ to GND}$ ,  $C_L = 200\text{ pF to GND}$ ,  $V_{REFIN} = V_{DD}$ . All specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Temperature range is  $-55^\circ\text{C to }+125^\circ\text{C}$ , typical at  $+25^\circ\text{C}$ .

Table 2.

Parameter <sup>1</sup>	Min	Typ	Max	Unit	Conditions/Comments
Output Voltage Settling Time		6	10	$\mu\text{s}$	$\frac{1}{4}$ to $\frac{3}{4}$ scale settling to $\pm 2$ LSB
Slew Rate		1.5		$\text{V}/\mu\text{s}$	
Digital-to-Analog Glitch Impulse		4		$\text{nV}\cdot\text{sec}$	1 LSB change around major carry (see Figure 24)
Digital Feedthrough		0.1		$\text{nV}\cdot\text{sec}$	
Reference Feedthrough		-90		$\text{dB}$	$V_{REF} = 2\text{ V} \pm 0.1\text{ V p-p}$ , frequency = 10 Hz to 20 MHz
Digital Crosstalk		0.5		$\text{nV}\cdot\text{sec}$	
Analog Crosstalk		2.5		$\text{nV}\cdot\text{sec}$	
DAC-to-DAC Crosstalk		3		$\text{nV}\cdot\text{sec}$	
Multiplying Bandwidth		340		$\text{kHz}$	$V_{REF} = 2\text{ V} \pm 0.2\text{ V p-p}$
Total Harmonic Distortion		-80		$\text{dB}$	$V_{REF} = 2\text{ V} \pm 0.1\text{ V p-p}$ , frequency = 10 kHz
Output Noise Spectral Density		120		$\text{nV}/\sqrt{\text{Hz}}$	DAC code = 0x8400, 1 kHz
		100		$\text{nV}/\sqrt{\text{Hz}}$	DAC code = 0x8400, 10 kHz
Output Noise		15		$\mu\text{V p-p}$	0.1 Hz to 10 Hz

<sup>1</sup> Guaranteed by design and characterization; not production tested.

**TIMING CHARACTERISTICS**

All input signals are specified with  $t_r = t_f = 1 \text{ ns/V}$  (10% to 90% of  $V_{DD}$ ) and timed from a voltage level of  $(V_{IL} + V_{IH})/2$ . See Figure 2.  $V_{DD} = 2.7 \text{ V}$  to  $5.5 \text{ V}$ . All specifications  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.

Table 3.

Parameter	Limit at $T_{MIN}, T_{MAX}$ $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$	Unit	Conditions/Comments
$t_1^1$	20	ns min	SCLK cycle time
$t_2$	8	ns min	SCLK high time
$t_3$	8	ns min	SCLK low time
$t_4$	13	ns min	$\overline{\text{SYNC}}$ to SCLK falling edge set-up time
$t_5$	4	ns min	Data setup time
$t_6$	4	ns min	Data hold time
$t_7$	0	ns min	SCLK falling edge to $\overline{\text{SYNC}}$ rising edge
$t_8$	15	ns min	Minimum $\overline{\text{SYNC}}$ high time
$t_9$	13	ns min	$\overline{\text{SYNC}}$ rising edge to SCLK fall ignore
$t_{10}$	0	ns min	SCLK falling edge to $\overline{\text{SYNC}}$ fall ignore
$t_{11}$	10	ns min	$\overline{\text{LDAC}}$ pulse width low
$t_{12}$	15	ns min	SCLK falling edge to $\overline{\text{LDAC}}$ rising edge
$t_{13}$	5	ns min	$\overline{\text{CLR}}$ pulse width low
$t_{14}$	0	ns min	SCLK falling edge to $\overline{\text{LDAC}}$ falling edge
$t_{15}$	300	ns typ	$\overline{\text{CLR}}$ pulse activation time

<sup>1</sup> Maximum SCLK frequency is 50 MHz at  $V_{DD} = 2.7 \text{ V}$  to  $5.5 \text{ V}$ . Guaranteed by design and characterization; not production tested.

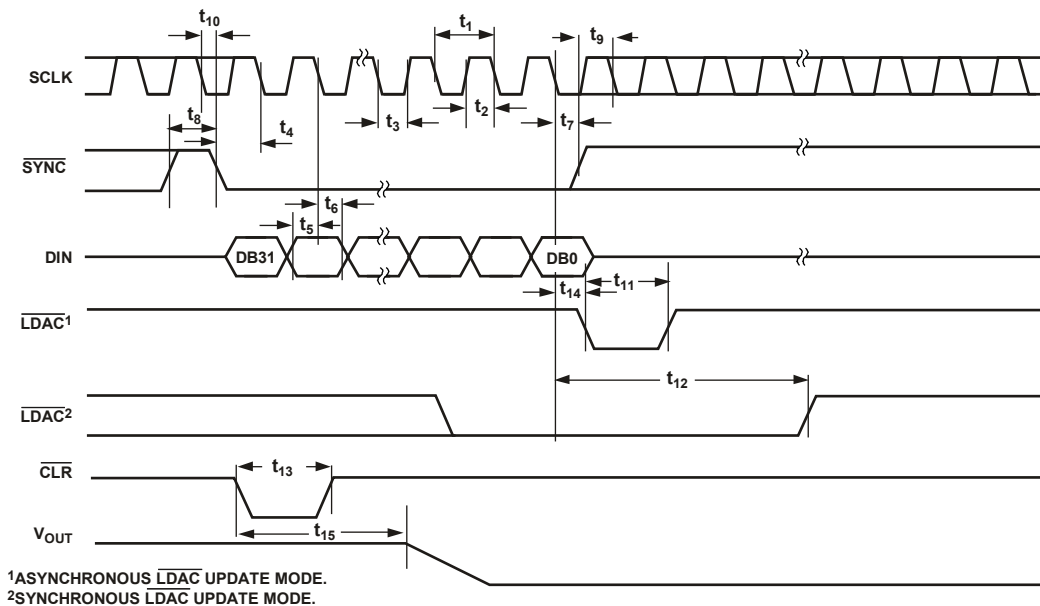


Figure 2. Serial Write Operation

094E3-002

## ABSOLUTE MAXIMUM RATINGS

T<sub>A</sub> = 25°C, unless otherwise noted.

Table 4.

Parameter	Rating
V <sub>DD</sub> to GND	−0.3 V to +7 V
Digital Input Voltage to GND	−0.3 V to V <sub>DD</sub> + 0.3 V
V <sub>OUT</sub> to GND	−0.3 V to V <sub>DD</sub> + 0.3 V
V <sub>REFIN</sub> /V <sub>REFOUT</sub> to GND	−0.3 V to V <sub>DD</sub> + 0.3 V
Operating Temperature Range Industrial	−55°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature (T <sub>J MAX</sub> )	150°C
TSSOP Package	
Power Dissipation	(T <sub>J MAX</sub> − T <sub>A</sub> )/θ <sub>JA</sub>
θ <sub>JA</sub> Thermal Impedance	150.4°C/W
Reflow Soldering Peak Temperature	
SnPb	240°C
Pb Free	260°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

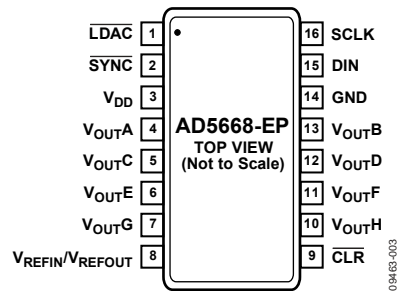


Figure 3. Pin Configuration

Table 5. Pin Function Descriptions

Pin Number	Mnemonic
1	LDAC
2	SYNC
3	V <sub>DD</sub>
4	V <sub>OUTA</sub>
5	V <sub>OUTC</sub>
6	V <sub>OUTE</sub>
7	V <sub>OUTG</sub>
8	V <sub>REFIN</sub> /V <sub>REFOUT</sub>
9	CLR
10	V <sub>OUTH</sub>
11	V <sub>OUTF</sub>
12	V <sub>OUTD</sub>
13	V <sub>OUTB</sub>
14	GND
15	DIN
16	SCLK

## TYPICAL PERFORMANCE CHARACTERISTICS

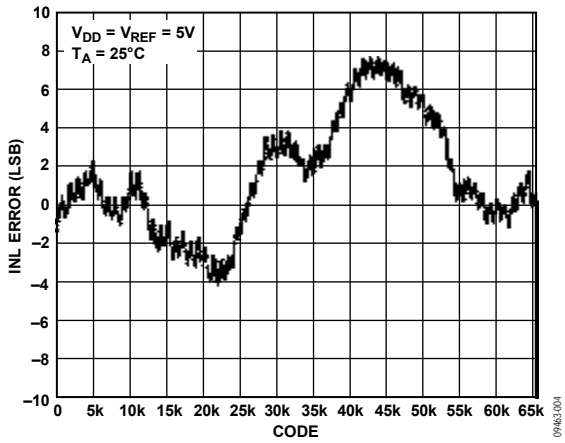


Figure 4. INL—External Reference

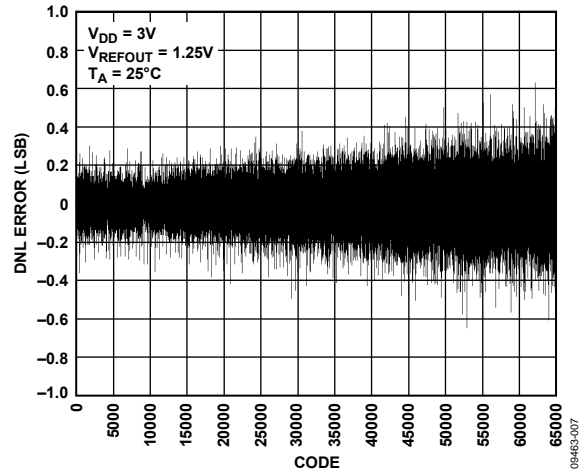


Figure 7. DNL

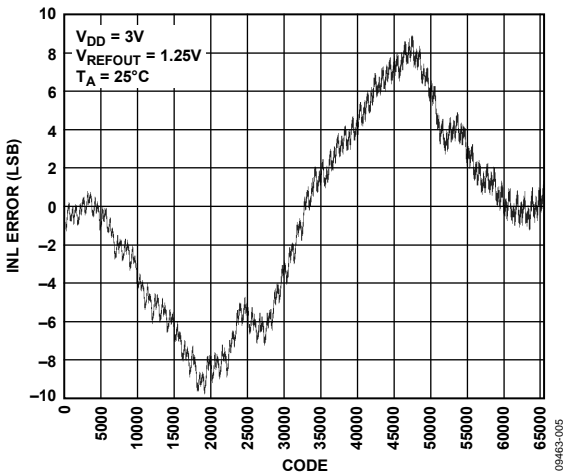


Figure 5. INL

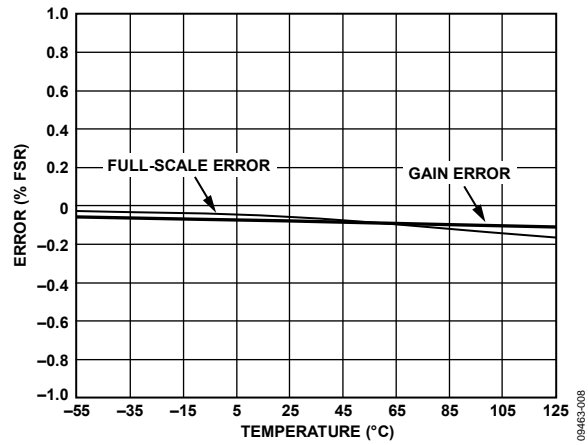


Figure 8. Gain Error and Full-Scale Error vs. Temperature

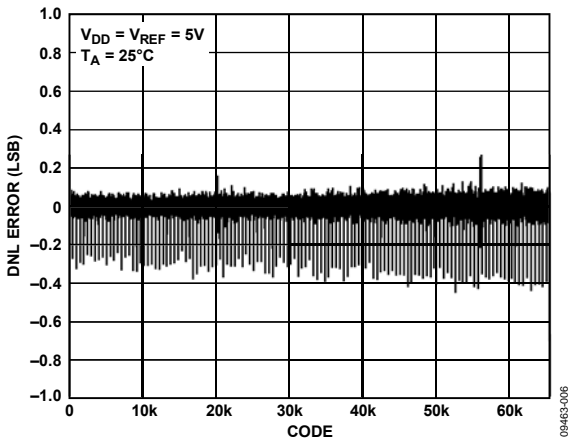


Figure 6. DNL—External Reference

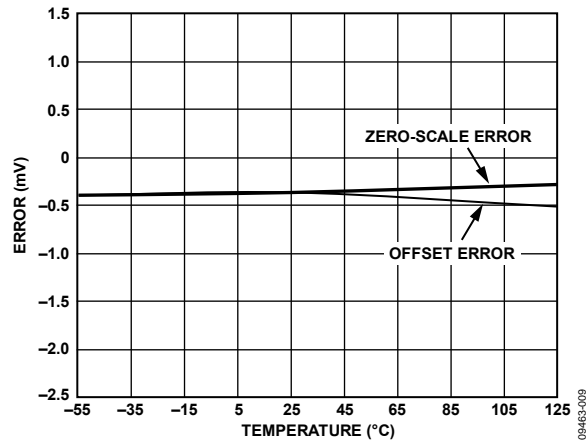


Figure 9. Zero-Scale Error and Offset Error vs. Temperature



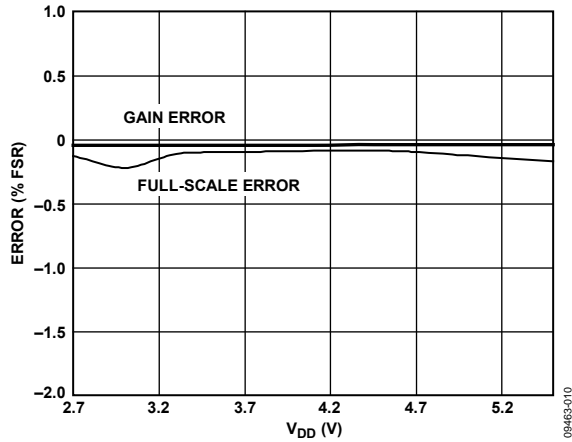


Figure 10. Gain Error and Full-Scale Error vs. Supply Voltage

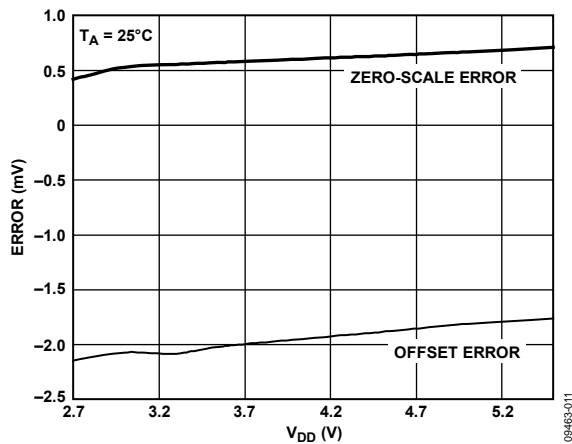


Figure 11. Zero-Scale Error and Offset Error vs. Supply Voltage

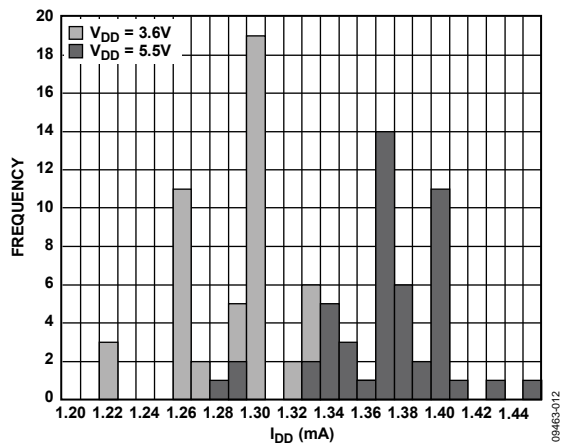


Figure 12. I<sub>DD</sub> Histogram with External Reference

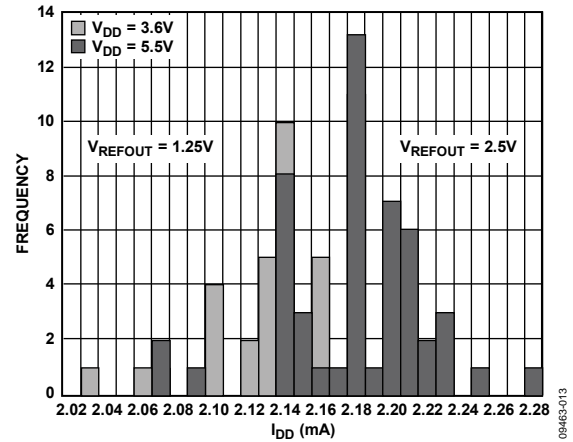


Figure 13. I<sub>DD</sub> Histogram with Internal Reference

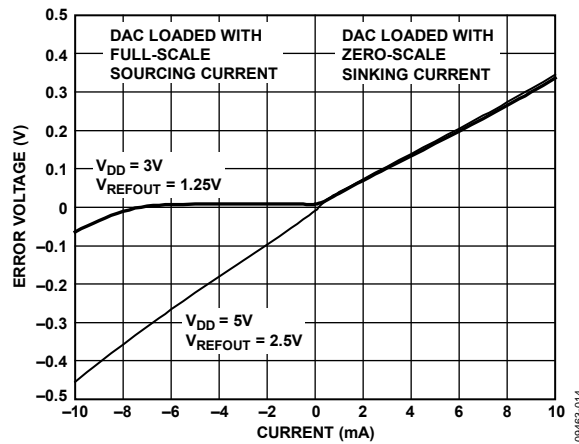


Figure 14. Headroom at Rails vs. Source and Sink

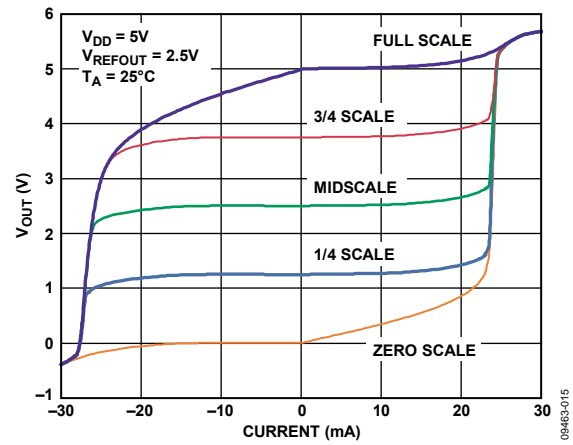


Figure 15. Source and Sink Capability

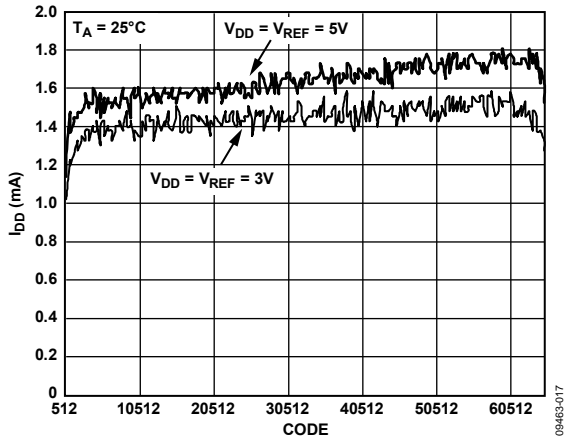


Figure 16. Supply Current vs. Code

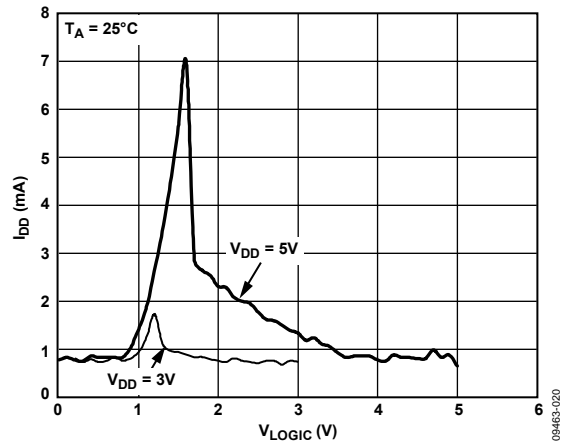


Figure 19. Supply Current vs. Logic Input Voltage

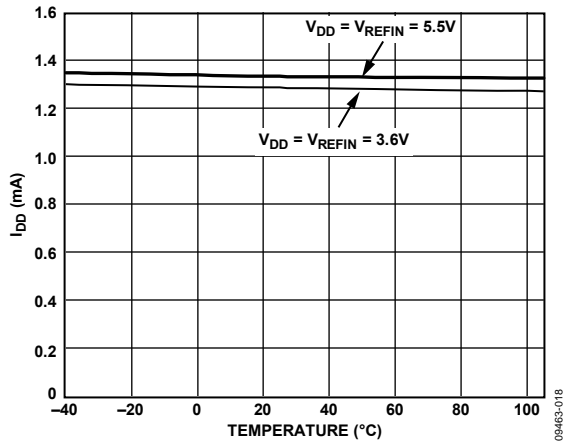


Figure 17. Supply Current vs. Temperature

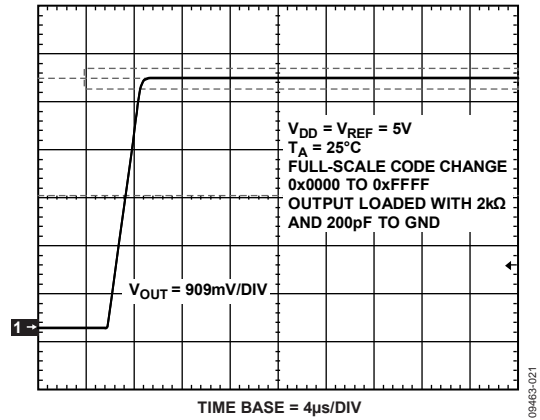


Figure 20. Full-Scale Settling Time, 5 V

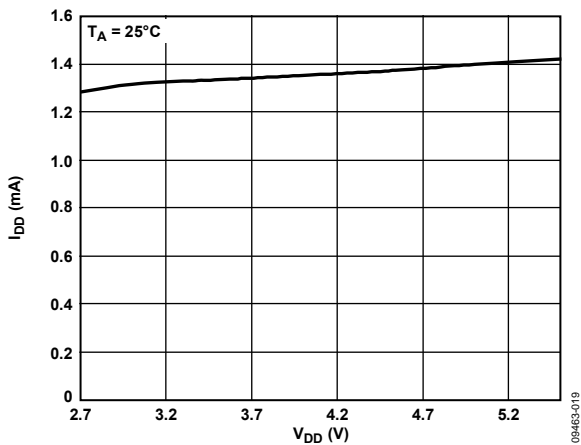


Figure 18. Supply Current vs. Supply Voltage

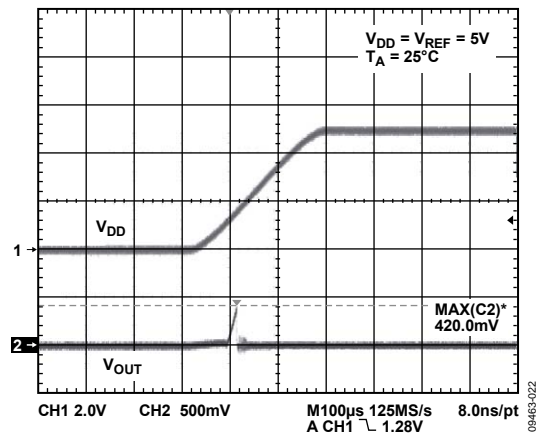


Figure 21. Power-On Reset to 0 V

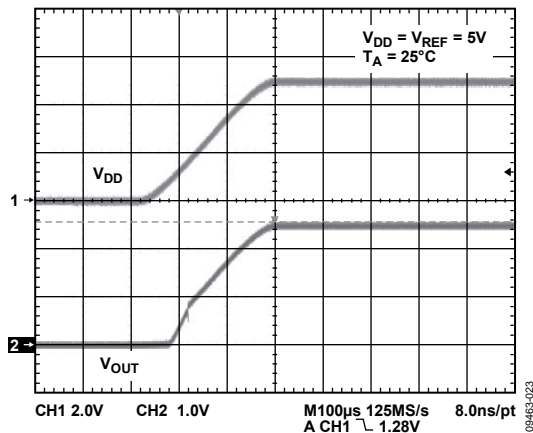


Figure 22. Power-On Reset to Midscale

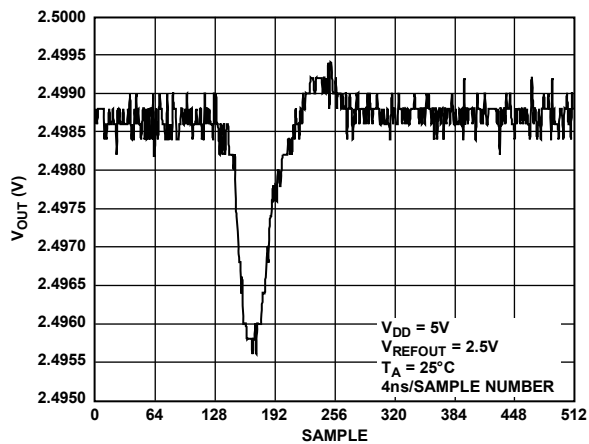


Figure 25. Analog Crosstalk

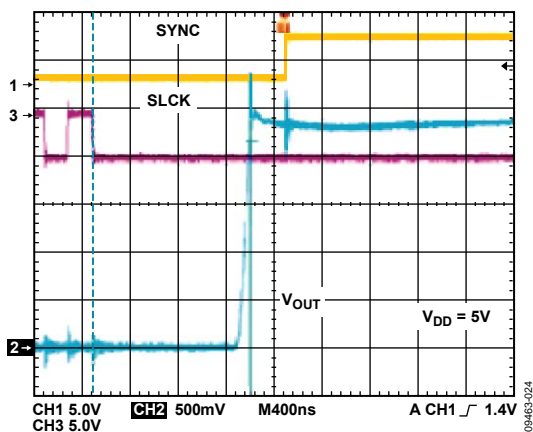


Figure 23. Exiting Power-Down to Midscale

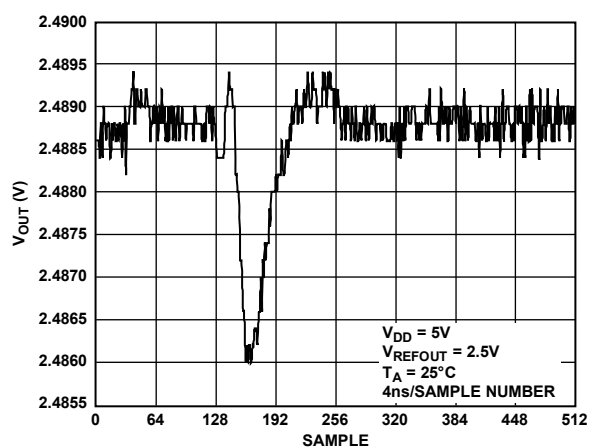


Figure 26. DAC-to-DAC Crosstalk

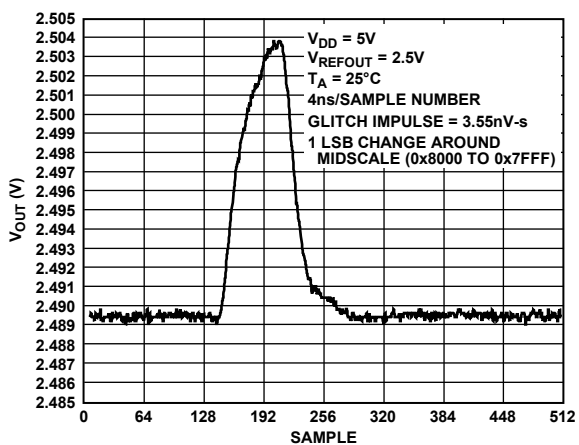


Figure 24. Digital-to-Analog Glitch Impulse (Negative)

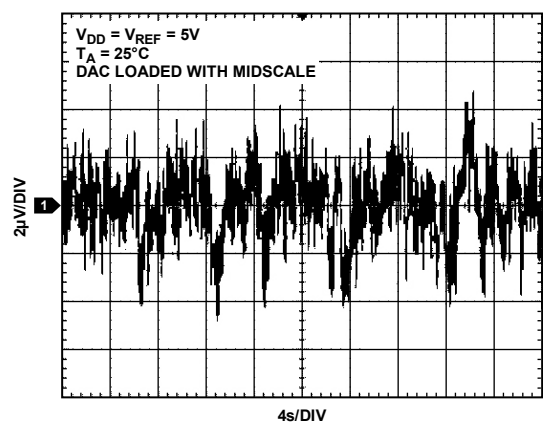


Figure 27. 0.1 Hz to 10 Hz Output Noise Plot, External Reference

# AD5668-EP

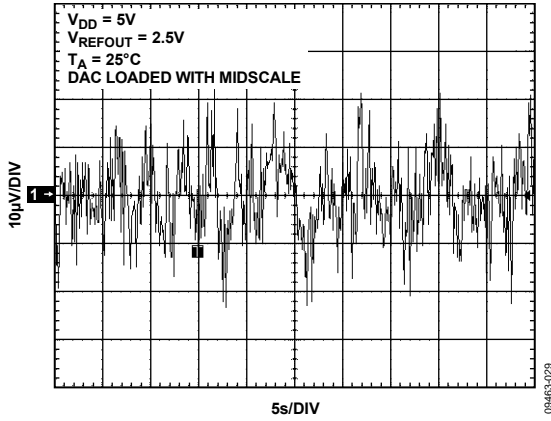


Figure 28. 0.1 Hz to 10 Hz Output Noise Plot, Internal Reference

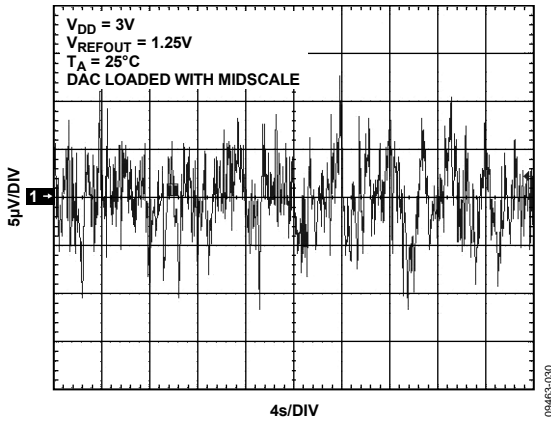


Figure 29. 0.1 Hz to 10 Hz Output Noise Plot, Internal Reference

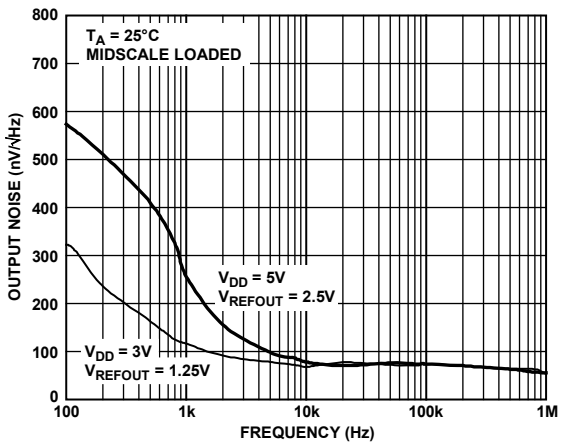


Figure 30. Noise Spectral Density, Internal Reference

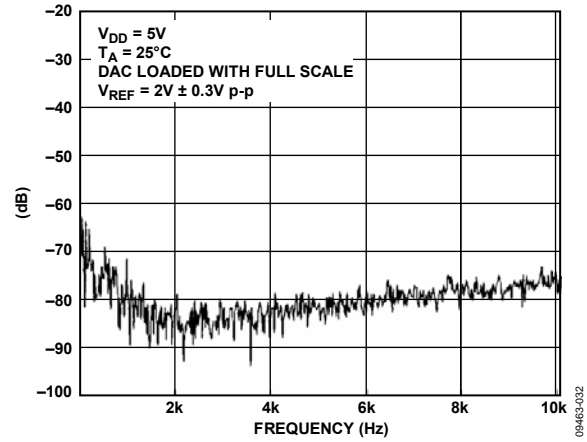


Figure 31. Total Harmonic Distortion

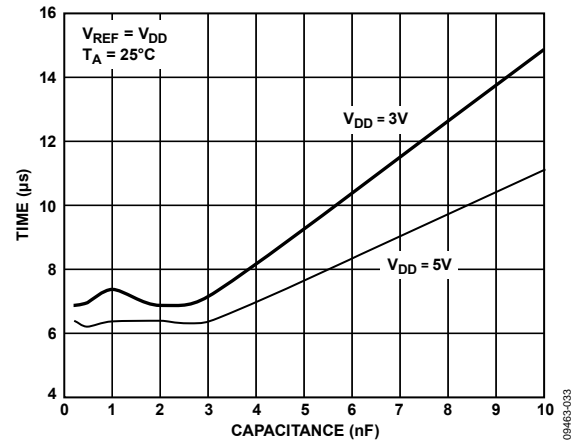


Figure 32. Settling Time vs. Capacitive Load

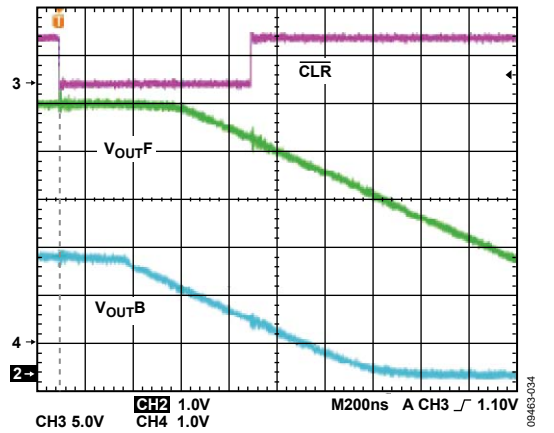


Figure 33. Hardware  $\overline{\text{CLR}}$

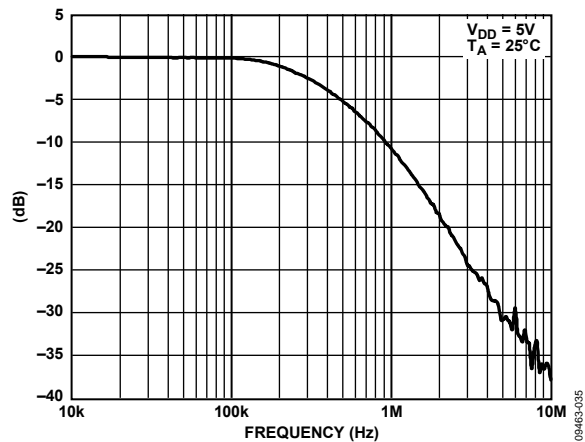
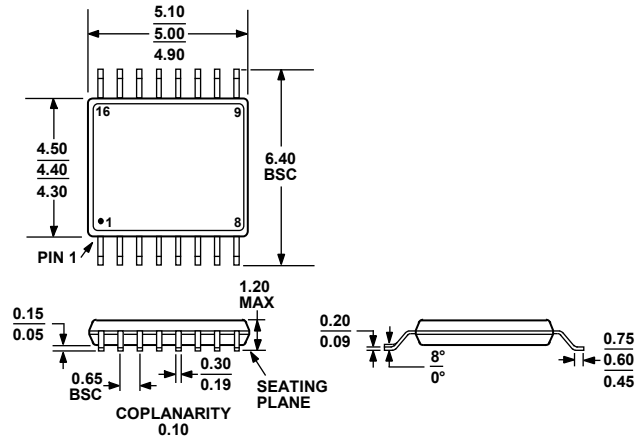


Figure 34. Multiplying Bandwidth

# AD5668-EP

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 35. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16)

Dimensions shown in millimeters

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Power-On Reset to Code	Accuracy	Internal Reference
AD5668SRU-EP-1RL7	-55°C to +125°C	16-Lead TSSOP	RU-16	Zero	±21 LSB INL	1.25 V

<sup>1</sup> Z = RoHS Compliant Part.

**NOTES**

**AD5668-EP**

**NOTES**